

-100V P-Channel Enhancement Mode MOSFET

Description

The SX8P10S uses advanced trench technology to provide excellent RDS(ON), low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

 $V_{DS} = -100V I_{D} = -8A$

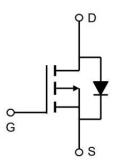
 $R_{DS(ON)}$ < -110m Ω @ V_{GS}=-10V

Application

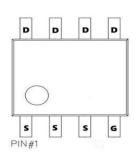
Battery protection

Load switch

Uninterruptible power supply







Absolute Maximum Ratings (T_c=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units	
Vos	Drain-Source Voltage	-100	V	
Vgs	Gate-Source Voltage ±20		V	
b@Tc=25°C	Continuous Drain Current, V _{GS} @ -10V ¹	Continuous Drain Current, V _{GS} @ -10V ¹ -8		
lo@Tc=100℃	Continuous Drain Current, V _{GS} @ -10V ¹ -3.85		А	
loм	Pulsed Drain Current ²	Pulsed Drain Current ² -18		
EAS	Single Pulse Avalanche Energy ³ 56		mJ	
las	Avalanche Current	3.1	Α	
P o@T c=25℃	Total Power Dissipation ⁴	3.1	W	
Тѕтс	Storage Temperature Range	-55 to 150	$^{\circ}$	
TJ	Operating Junction Temperature Range	-55 to 150	$^{\circ}$	
RөJA	Thermal Resistance Junction-Ambient ¹	59	°C/W	
Rejc	Thermal Resistance Junction-Case ¹	16	°C/W	

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-100V P-Channel Enhancement Mode MOSFET

Electrical Characteristics (TJ=25℃, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BVDSS	Drain-Source Breakdown Voltage	Vgs=0V , Ip=-250uA	-100	-110		V	
_	Static Drain-Source On-Resistance ²	Vgs=-10V , ID=- 6A		83	110	_	
RDS(ON)		Vgs=-4.5V , ID=-3A		95	120	mΩ	
VGS(th)	Gate Threshold Voltage	Vgs=Vds , Id =-250uA	-1.2	-1.8	-2.5	V	
loss	Drain-Source Leakage Current	Vps=-100V , Vgs=0V , TJ=25℃			-50	uA	
Igss	Gate-Source Leakage Current	Vgs=±20V , Vps=0V			±100	nA	
gfs	Forward Transconductance	Vps=-10V , Ip=-10A		24		S	
Qg	Total Gate Charge			20.1		nC	
Qgs	Gate-Source Charge	VDS=-50V , VGS=-10V , ID=-20A		3.9			
Qgd	Gate-Drain Charge			4.3			
Td(on)	Turn-On Delay Time			10			
Tr	Rise Time	V _{DD} =-50V , V _{GS} =-10V , R _G =3.3 ,		30		ns	
Td(off)	Turn-Off Delay Time	lp=-10A		77			
Tf	Fall Time	1 ID10A		81			
Ciss	Input Capacitance			1051			
Coss	Output Capacitance	V _{DS} =-20V , V _{GS} =0V , f=1MHz		119		pF	
Crss	Reverse Transfer Capacitance			25			
ls	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current			-15	Α	
Vsp	Diode Forward Voltage ²	Vgs=0V , Is=-1A , Tյ=25℃			-1.2	V	
trr	Reverse Recovery Time	I=-8A , di/dt=-100A/μs ,		81		nS	
Qrr	Reverse Recovery Charge	TJ=25°C		140		nC	

2

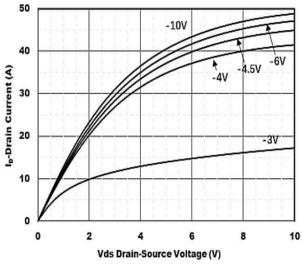
Notes:

- 1 Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
- 2 . The test condition is, VDD=80V,VG=10V RG =25 Ω , L=0.1mH.
- 3 . The data tested by pulsed Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%
- 4 . The power dissipation is limited by $150\,^\circ\!\!\mathrm{C}\,\text{junction}$ temperature

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Typical Characteristics



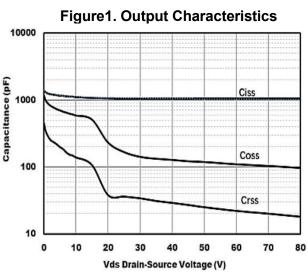


Figure 3. Capacitance Characteristics

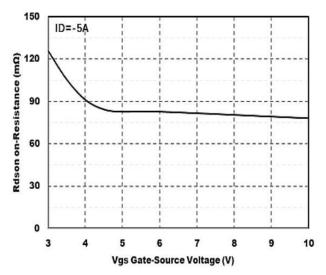
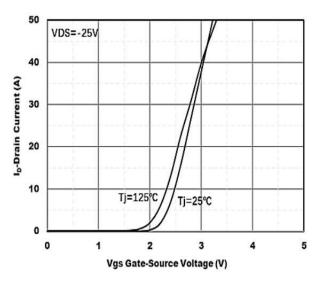
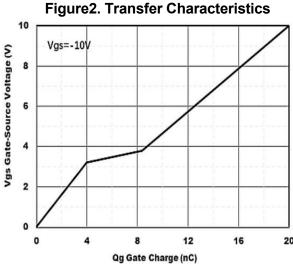


Figure 5. : On-Resistance vs. Gate to Source





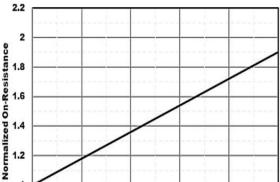


Figure 4. Gate Charge



75

0.8

3

25

50

Figure 6. Normalized On-Resistance Voltage

 T_J -Junction Temperature (°C)

100

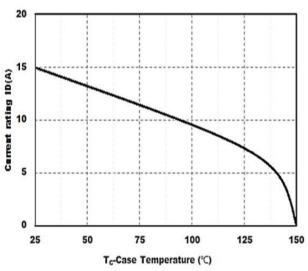
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125

150



Typical Characteristics



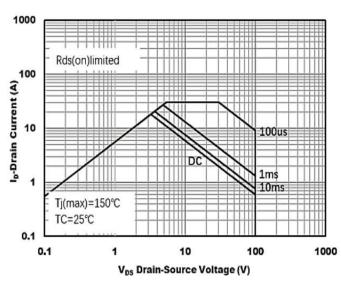


Figure7. Drain current

Figure 8. Safe Operation Area

-V_{DD}

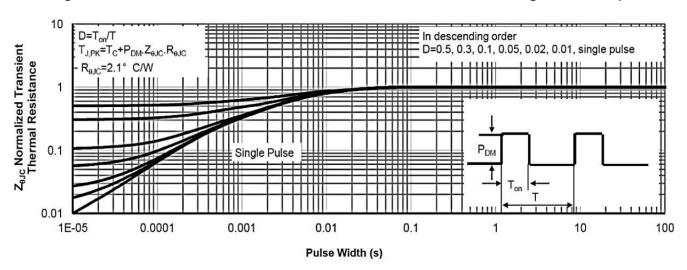
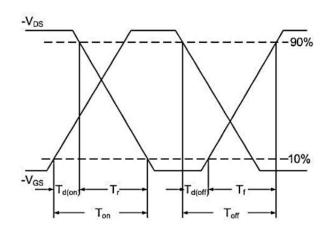


Figure 9. Normalized Maximum Transient thermal impedance

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-V_{GS}

EAS= $\frac{1}{2}$ L x (- I_{AS}^2)x $\frac{-BV_{DSS}}{-BV_{DSS}-(-V_{DD})}$

Figure 10 Switching Time Waveform

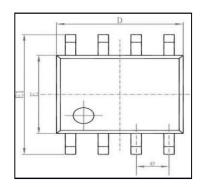
Figure11 Unclamped Inductive Waveform

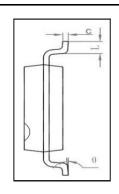
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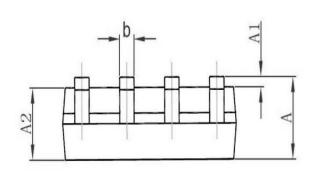




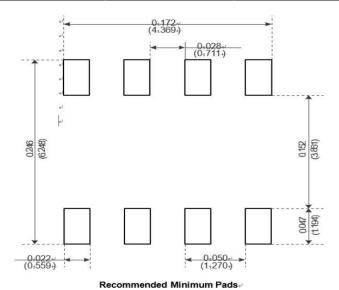
Package Mechanical Data-SOP-8







Symbol	Dimensions I	n Millimeters	Dimensions	In Inches
	Min	Max	Min	Max
Α	1.350	1. 750	0. 053	0.069
A1	0. 100	0. 250	0.004	0.010
A2	1. 350	1. 550	0.053	0. 061
b	0. 330	0. 510	0.013	0. 020
С	0. 170	0. 250	0.006	0.010
D	4. 700	5. 100	0. 185	0. 200
E	3. 800	4. 000	0. 150	0. 157
E1	5. 800	6. 200	0. 228	0. 244
е	1. 270 (BSC)		0. 050 (BSC)	(BSC)
L	0. 400	1. 270	0.016	0.050
θ	0°	8°	0°	8°



Package Marking and Ordering Information

dokage marking and ordering information					
Product ID	Pack	Marking	Qty(PCS)		
TAPING	SOP-8		3000		

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